



STPS3045CT/CG/CR/CP/CPI/CW/CFP

POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_F(AV)$	2 x 15 A
V_{RRM}	45 V
$T_j(max)$	175 °C
V_F	0.57 V

FEATURES AND BENEFITS

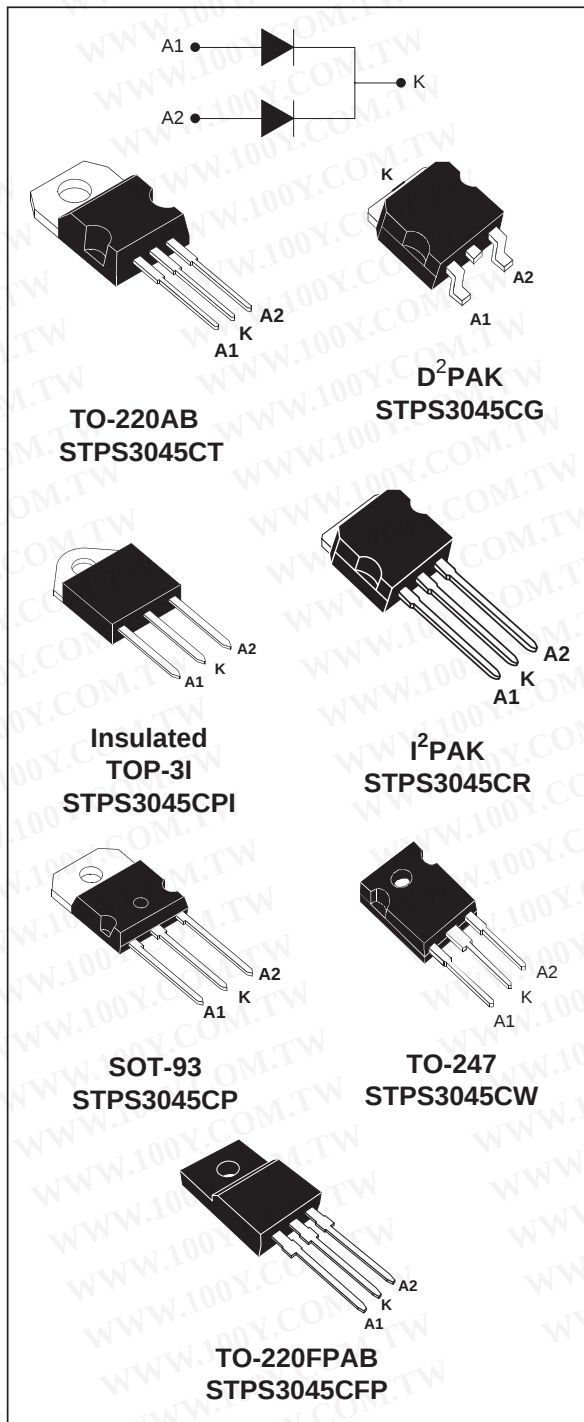
- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW THERMAL RESISTANCE
- INSULATED PACKAGE: TOP-3I
Insulating voltage = 2500V RMS
Capacitance = 12pF
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Dual center tap Schottky rectifier suited for SwitchMode Power Supply and high frequency DC to DC converters.

Packaged either in TO-220AB, TO-220FPAB, D²PAK, I²PAK, TO-247, SOT93 or TOP-3I, this device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

勝特力材料 886-3-5753170
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ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			45	V
I _{F(RMS)}	RMS forward current			30	A
I _{F(AV)}	Average forward current $\delta = 0.5$	TO-220AB / D ² PAK / I ² PAK / SOT-93 / TO-247	T _c = 155°C	Per diode Per device	15 30 A
		TO-220FPAB	T _c = 130°C		
		TOP-3I	T _c = 150°C		
I _{FSM}	Surge non repetitive forward current			t _p = 10 ms sinusoidal	220 A
I _{RRM}	Repetitive peak reverse current			t _p = 2 μ s square F = 1kHz	1 A
I _{RSM}	Non repetitive peak reverse current			t _p = 100 μ s square	3 A
P _{ARM}	Repetitive peak avalanche power			t _p = 1 μ s T _j = 25°C	6000 W
T _{stg}	Storage temperature range			-65 to +175	°C
T _j	Maximum operating junction temperature *			175	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/ μ s

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case	TO-220AB / D ² PAK / I ² PAK	Per diode Total	1.60 0.85	°C/W
		SOT-93 / TO-247	Per diode Total	1.5 0.8	
		TO-220FPAB	Per diode Total	4 3.2	
		TOP-3I	Per diode Total	2.2 1.6	
R _{th(c)}		TO-220AB / D ² PAK / I ² PAK SOT-93 / TO-247	Coupling	0.10	
		TO-220FPAB	Coupling	2.5	
		TOP-3I	Coupling	1.0	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j (\text{diode 1}) = P (\text{diode 1}) \times R_{th(j-c)} (\text{per diode}) + P (\text{diode 2}) \times R_{th(c)}$$

STATIC ELECTRICAL CHARACTERISTICS (Per diode)

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}			200	μ A
		T _j = 125°C			11	40	mA
V _F *	Forward voltage drop	T _j = 125°C	I _F = 15 A		0.5	0.57	V
		T _j = 25°C	I _F = 30 A			0.84	
		T _j = 125°C	I _F = 30 A		0.65	0.72	

Pulse test : * t_p = 380 μ s, $\delta < 2\%$

To evaluate the conduction losses use the following equation :

$$P = 0.42 \times I_{F(AV)} + 0.01 I_{F(RMS)}^2$$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

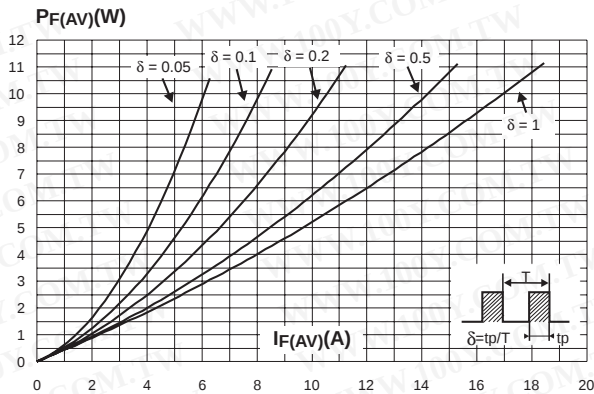


Fig. 2: Average current versus ambient temperature ($\delta = 0.5$, per diode).

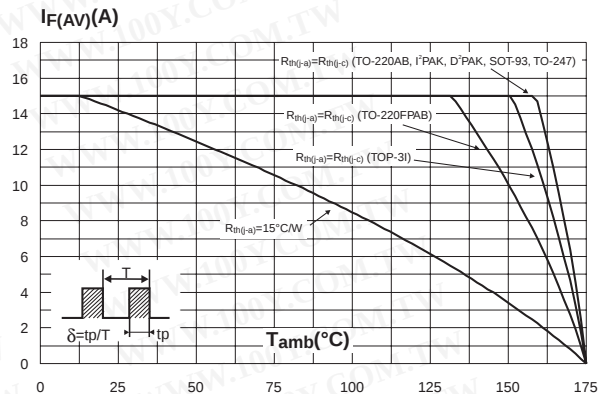


Fig. 3: Normalized avalanche power derating versus pulse duration.

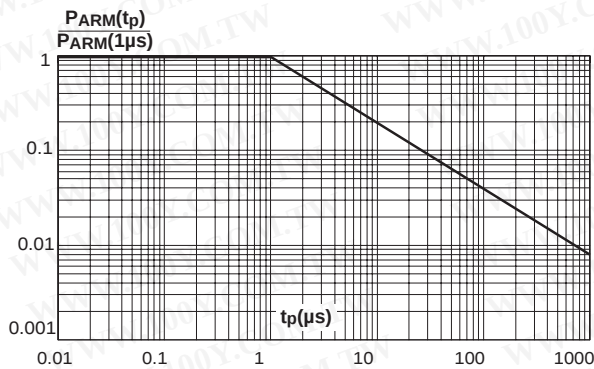


Fig. 4: Normalized avalanche power derating versus junction temperature.

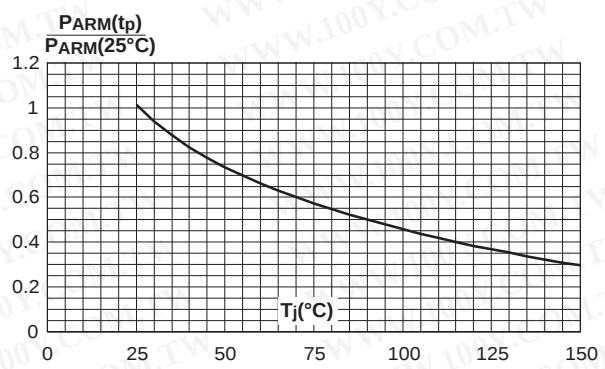


Fig. 5-1: Non repetitive surge peak forward current versus overload duration (maximum values, per diode).

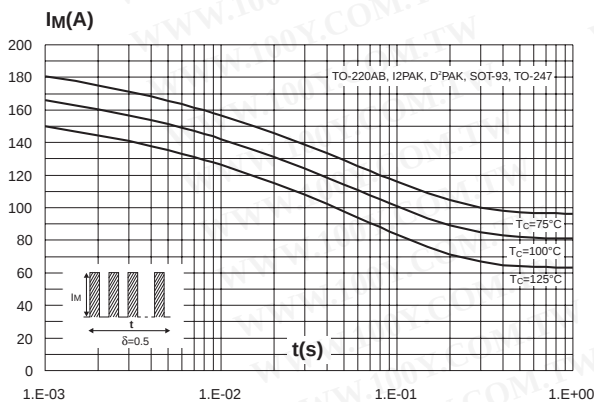
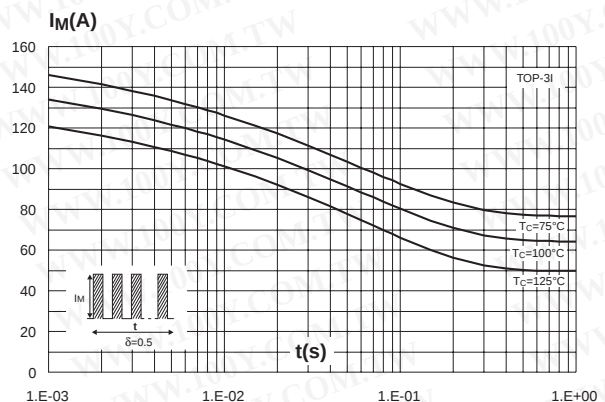


Fig. 5-2: Non repetitive surge peak forward current versus overload duration (maximum values, per diode).



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Fig. 5-3: Non repetitive surge peak forward current versus overload duration (maximum values, per diode).

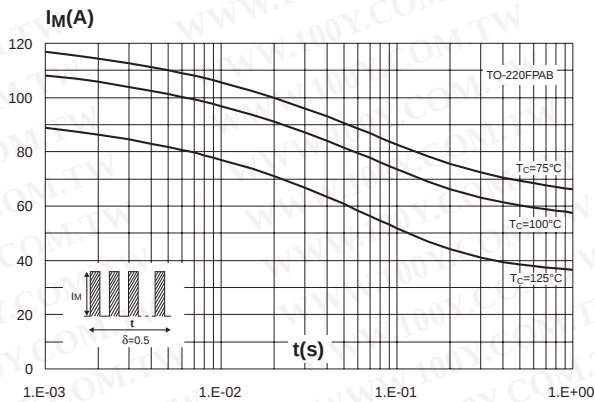


Fig. 6-1: Relative variation of thermal transient impedance junction to case versus pulse duration.

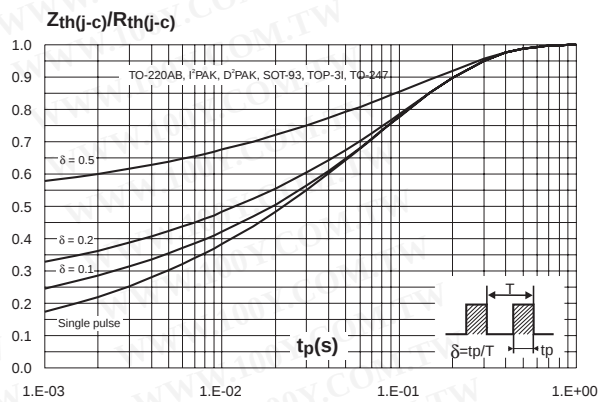


Fig. 6-2: Relative variation of thermal transient impedance junction to case versus pulse duration.

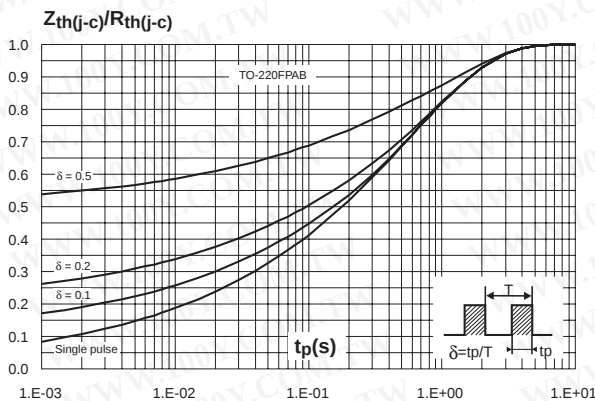


Fig. 7: Reverse leakage current versus reverse voltage applied (typical values, per diode).

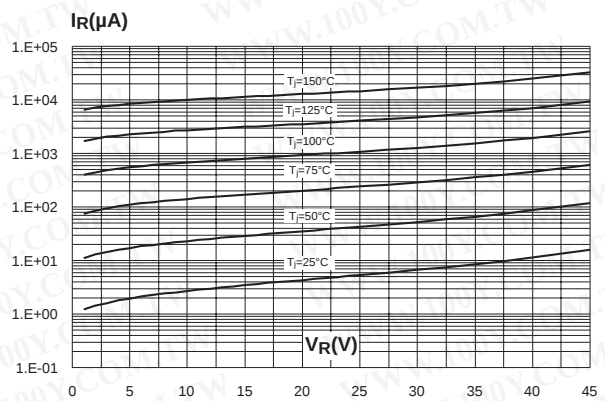


Fig. 8: Junction capacitance versus reverse voltage applied (typical values, per diode).

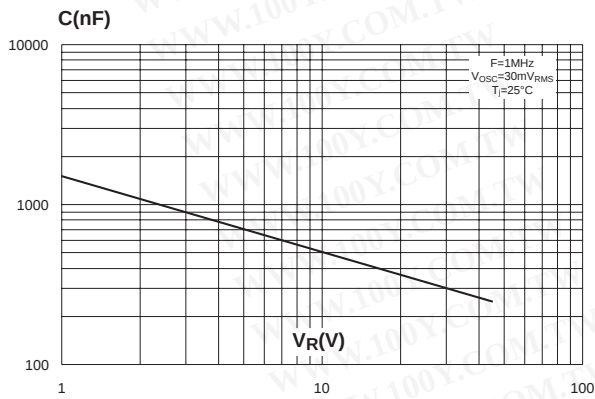


Fig. 9: Forward voltage drop versus forward current (maximum values, per diode).

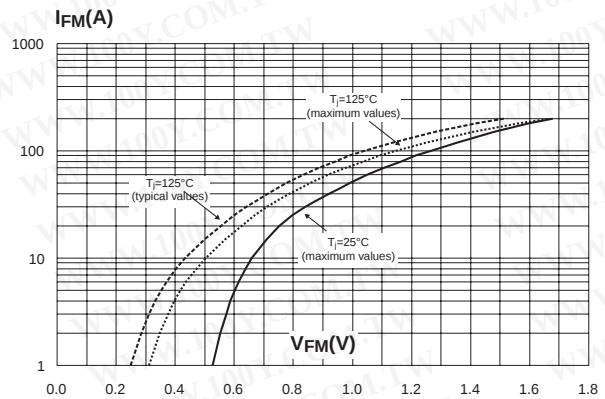
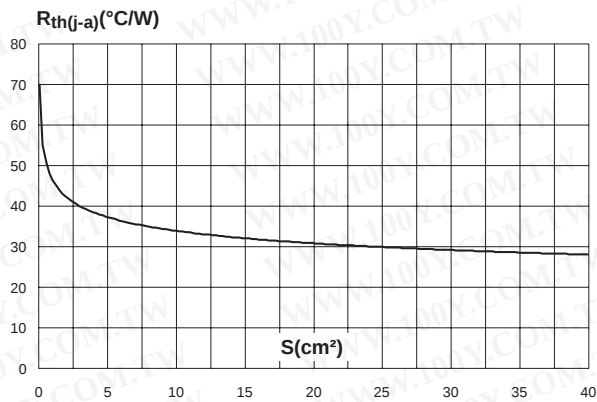
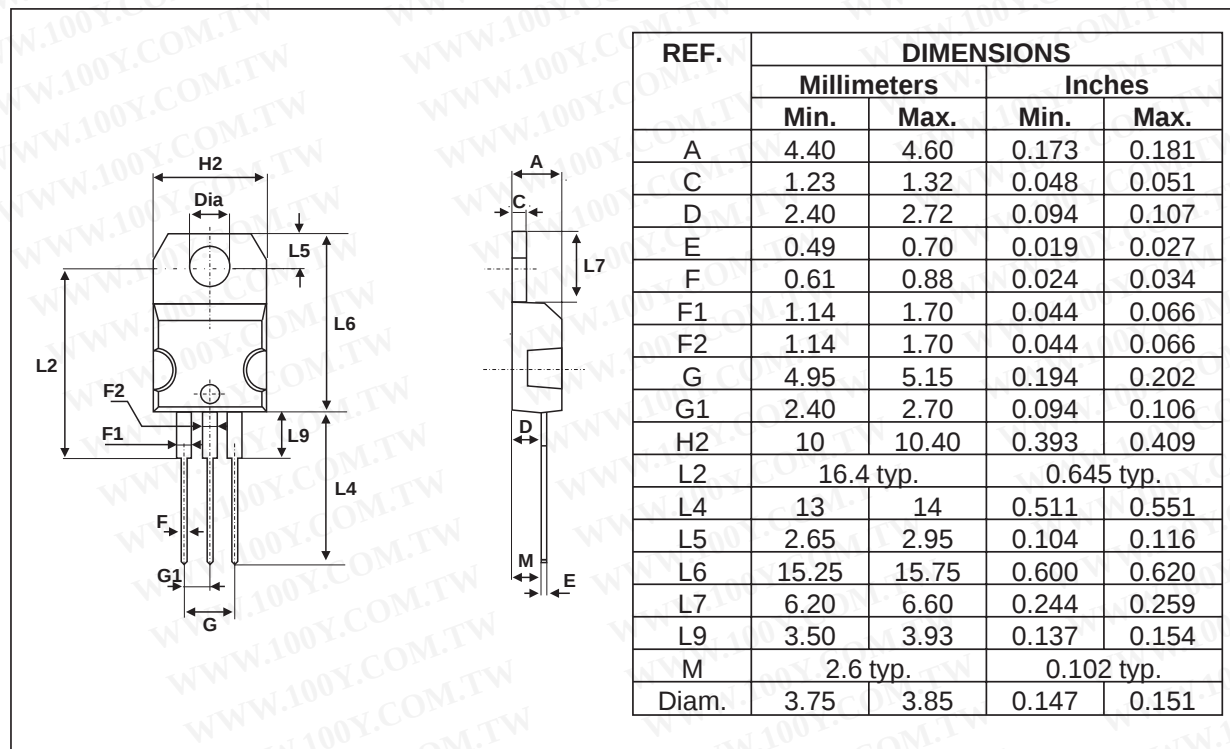


Fig. 10: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, Cu=35μm).



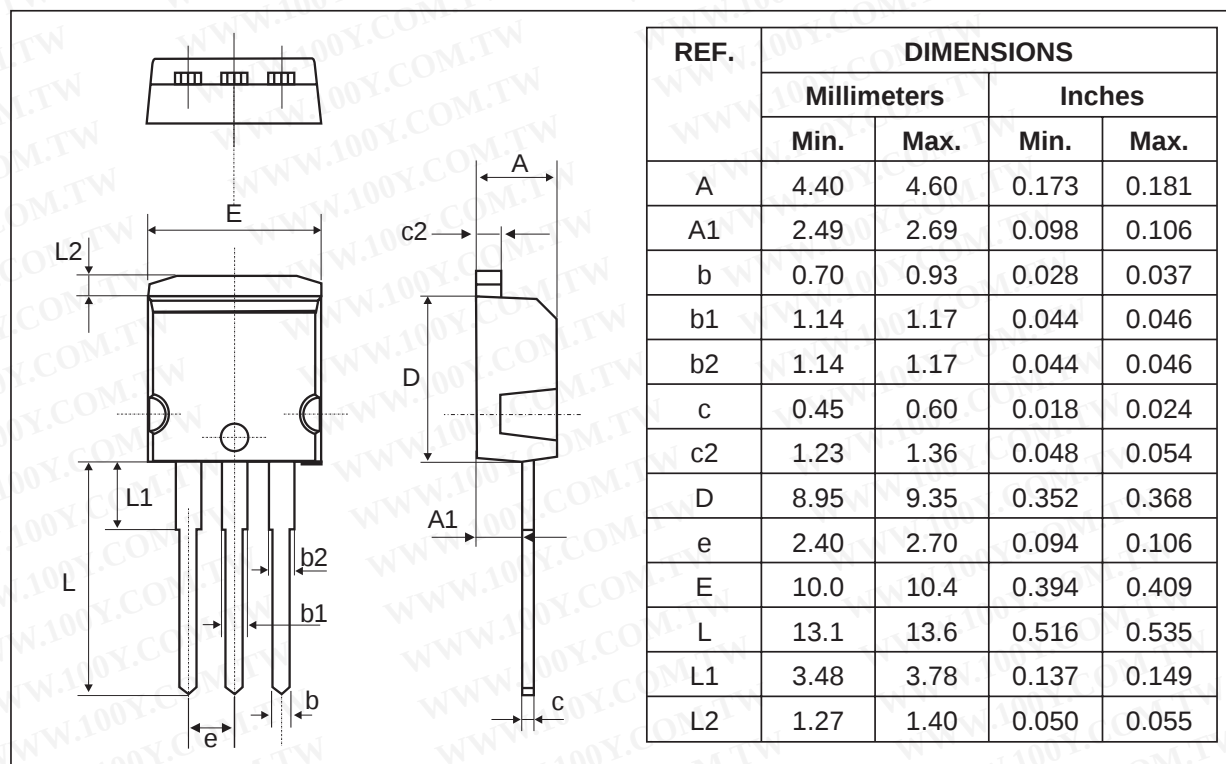
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PACKAGE MECHANICAL DATA
TO-220AB



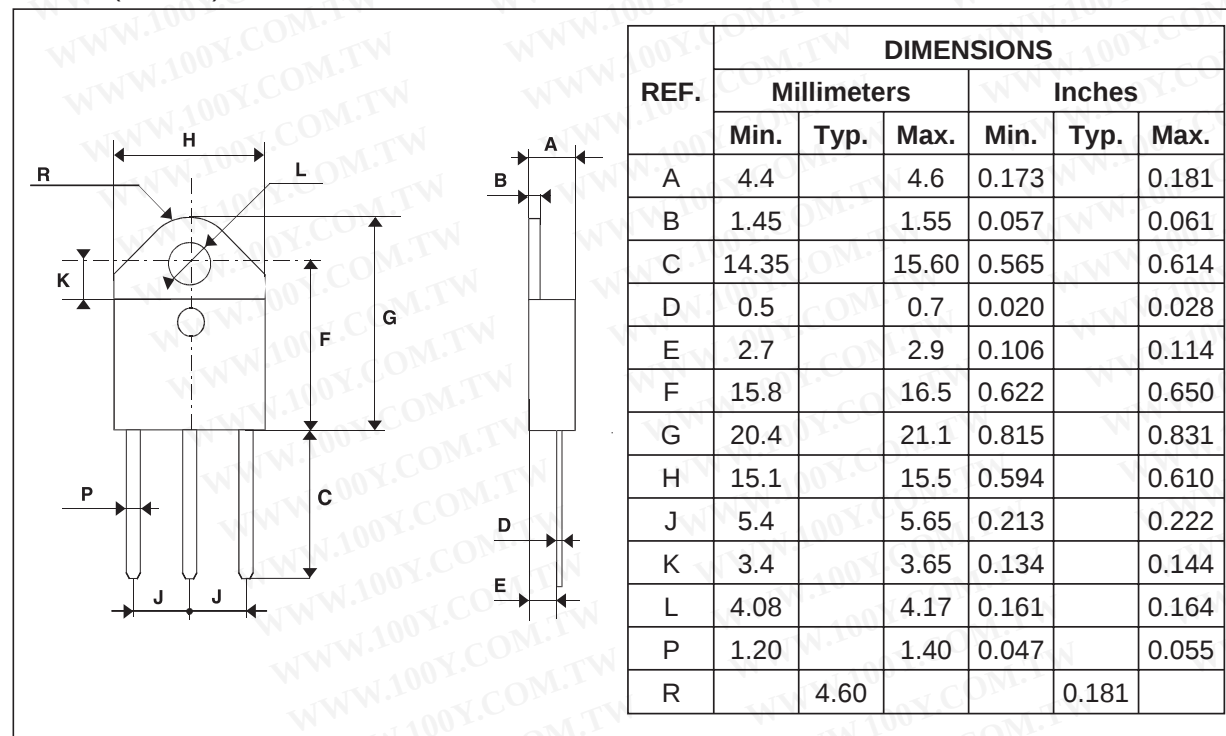
PACKAGE MECHANICAL DATA

I²PAK

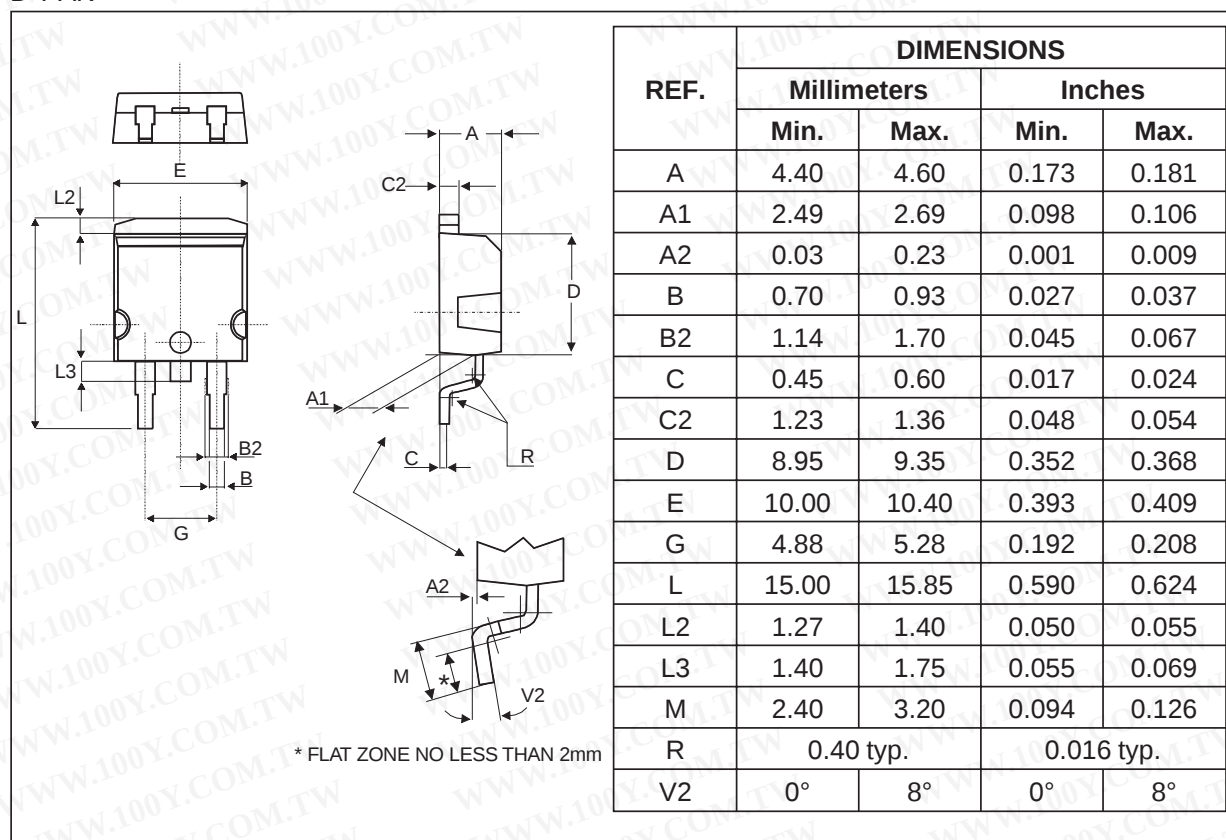


PACKAGE MECHANICAL DATA

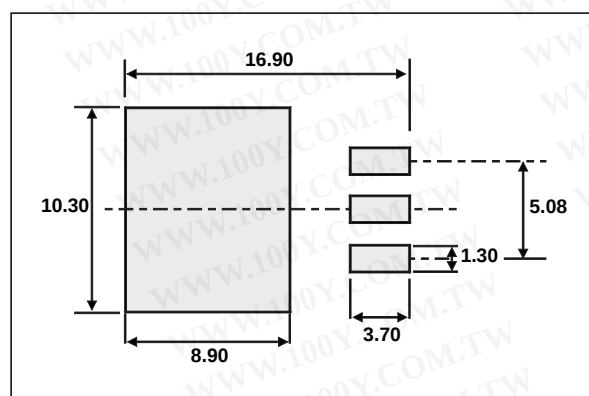
TOP-3I (isolated)



PACKAGE MECHANICAL DATA

D²PAK

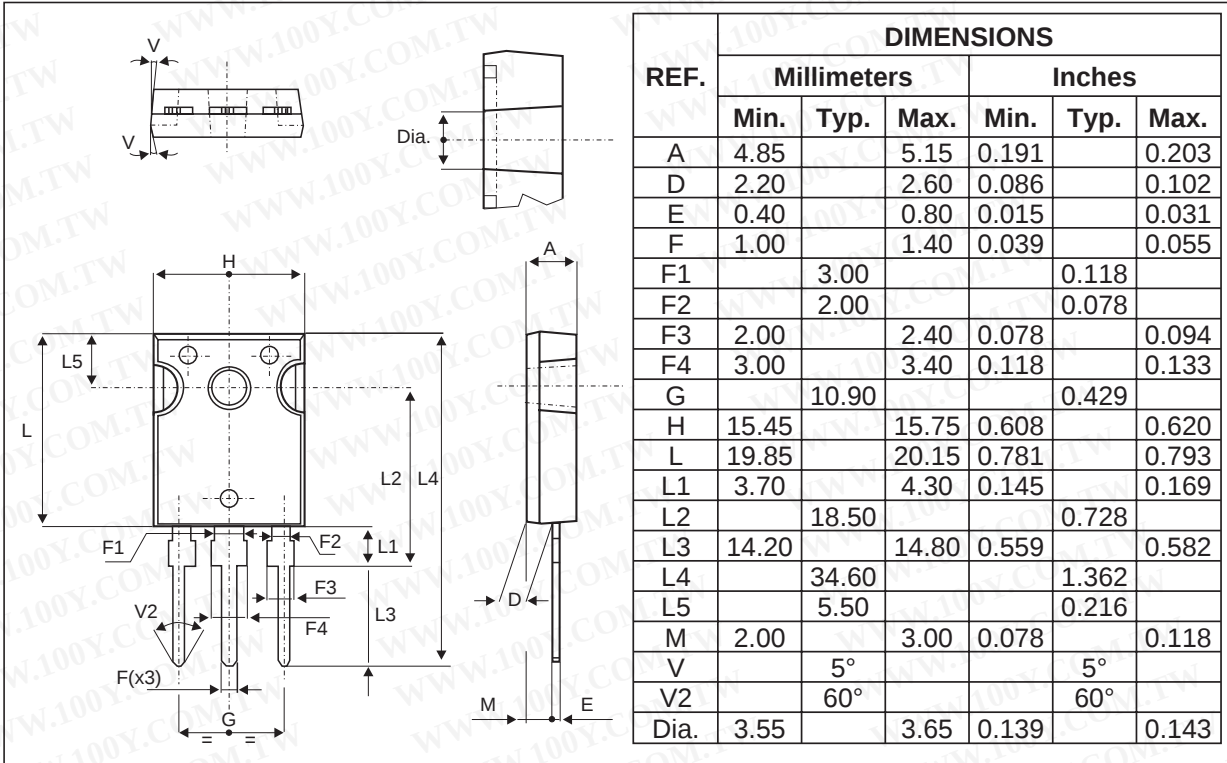
FOOTPRINT DIMENSIONS (in millimeters)



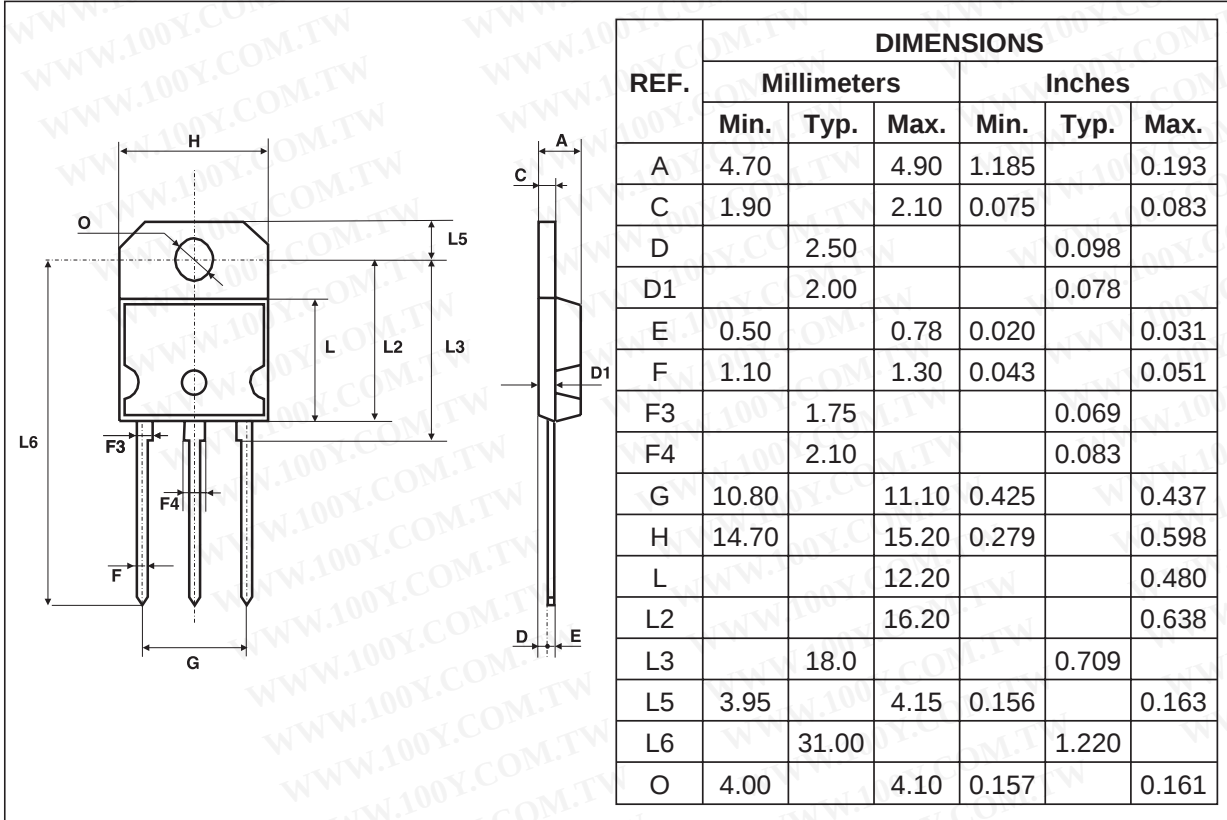
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PACKAGE MECHANICAL DATA
TO-247



PACKAGE MECHANICAL DATA
SOT-93



PACKAGE MECHANICAL DATA
TO-220FPAB

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

Type	Marking	Package	Weight	Base qty	Delivery mode
STPS3045CT	STPS3045CT	TO-220AB	2.23 g.	50	Tube
STPS3045CG	STPS3045CG	D ² PAK	1.48 g.	50	Tube
STPS3045CG-TR	STPS3045CG	D ² PAK	1.48 g.	1000	Tape & reel
STPS3045CR	STPS3045CR	I ² PAK	1.48 g.	50	Tube
STPS3045CP	STPS3045CP	SOT-93	3.97 g.	30	Tube
STPS3045CPI	STPS3045CPI	TOP-3I	4.46 g.	120	Bulk
STPS3045CW	STPS3045CW	TO-247	4.46 g.	30	Tube
STPS3045CFP	STPS3045CFP	TO-220FPAB	2.0 g.	50	Tube

- Cooling method: by conduction (C)
- Recommended torque value (SOT-93, TOP-3I, TO-247): 0.8 N.m.
- Recommended torque value (TO-220AB): 0.55 N.m.
- Maximum torque value (SOT-93, TOP-3I, TO-247): 1.0 N.m.
- Maximum torque value (TO-220AB): 0.7 N.m.

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